Notes

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Introduction

The RC32434/5 is a high performance, general-purpose, integrated processor that incorporates a 32-bit CPU core with a number of on-chip peripherals including:

– *A memory controller supporting DDR SDRAM*
– *A separate memory/peripheral controller interfacing to EPROM, flash, and I/O peripherals*
– *One Ethernet MAC*
– *32-bit v.2.2 compatible PCI interface*
– *Other generic modules, such as a serial port, SPI, interrupt controller, GPIO, and DMA.*

Internally, the RC32434/5 features a dual bus system. The CPU bus interfaces directly to the memory controller over a 32-bit bus running at CPU pipeline speed. Since it is not possible to run an external bus at the speed of the CPU, the only way to provide data fast enough to keep the CPU from starving is to use either a wider DRAM or a double data rate DRAM.

As the memory technology used on PC motherboards transitions from SDRAM to DDR, the steep ramp-up in the volume of DDR memory being shipped is driving pricing to the point where DDR-based memory subsystems are primed to drop below those of traditional SDRAM modules. Anticipating this, IDT opted to incorporate a double data rate DRAM interface on its RC32434/5 integrated processor.

DDR memory requires a VDD/2 reference voltage and combination series and parallel terminations that SDRAM does not have. The board layout requirements for DDR are substantially more rigorous.

The purpose of this application note is to help designers select the proper components and design effective layouts to minimize the difficulty of using DDR memory. This application note will outline some of the key considerations a designer should be aware of when designing embedded applications that use this technology. It is assumed that the reader is already familiar with the basic concepts of DDR technology.

Interfacing with DDR Memory

The key features of the RC32434/5 DDR memory controller include:

◆ *Support for up to 256MB of DDR SDRAM*
◆ *Support for devices with densities of 64Mb, 128Mb, 256Mb, 512Mb, and 1Gb*
◆ *16-bit data bus width options to allow interfacing to 8 and 16 bit external memory devices*
◆ *Creation of differential clocking signals for external memory subsystem*

Critical Design Considerations

There are three major issues to consider when designing DDR-based subsystems:

– *Resistive signal termination schemes*
– *PCB signal routing requirements*
– *Generation and supply of required reference voltages.*

All three issues are critical to producing a reliable DDR-based memory subsystem, so designers must carefully address each.

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Resistor Terminations

There are several SSTL-2 approved termination methods that can be used with DDR. The choice is very much design-dependent.   Generally, single-series/single-parallel terminations work well with uni-directional signals, such as address lines. For bi-directional signals, double-series/double-parallel terminations usually produce slightly better results. However, it should be noted that since the double-series and/or double-parallel termination schemes require resistors or resistor packs on both ends of the signal, they invariably result in increased component counts, which slightly increases board cost.

Therefore, for most applications, IDT recommends that a single-series single-parallel termination scheme be used for both data and command signals. For clock signals, a pull-up resistor is not recommended. A single-series resistor between 10 and 33 ohms (associated with a 120 Ohm common mode resistor to eliminate any noise due to the differential pair) will provide the best results. Three different termination schemes are displayed in Figure 1.

These schemes have several benefits:

- *Reduced cost*
- *Simpler signal routing*
- *Reduced reflections*
- *Better signal bandwidth and settling.*

The range for the series resistor is between 10 and 33 ohms and the range for the parallel pull-up is between 25 and 56 ohms.[1]

The SSTL-2 Class II specification recommends a series resistor of 25 ohms and dual-parallel terminations of 50 ohms. Resistor packs specifically designed to meet this requirement are widely available. While other termination schemes will often produce superior noise margin, this configuration is usually adequate. However, it should be noted that IDT's DDR drivers are slightly below the strength defined for Class II drives. As a result, the total amplitude of the signal swing will be slightly reduced because the driver has to counter the 25 ohm parallel termination with less than the drive strength specified by Class II.   Although this will not cause a problem for most designs, IDT strongly recommends that designers wishing to lock themselves into this type of configuration through commercially available resistor packs first simulate the design using a signal integrity software package.

In general, regardless of which termination scheme is chosen, it is highly recommended that the board designer run signal integrity simulations. This allows the designer to determine the optimal resistor values for the specific board routing and memory configuration in question, resulting in a design with superior noise margins. Because the noise margins for SSTL-2 based drivers are very tight, any extra margin that can be eked out through tweaking the terminations is well worth pursuing.

[1.] When using double-parallel termination schemes, the values for the double-parallel pull-ups need to be doubled, since putting pull-ups in parallel effectively halves the pull-up value.
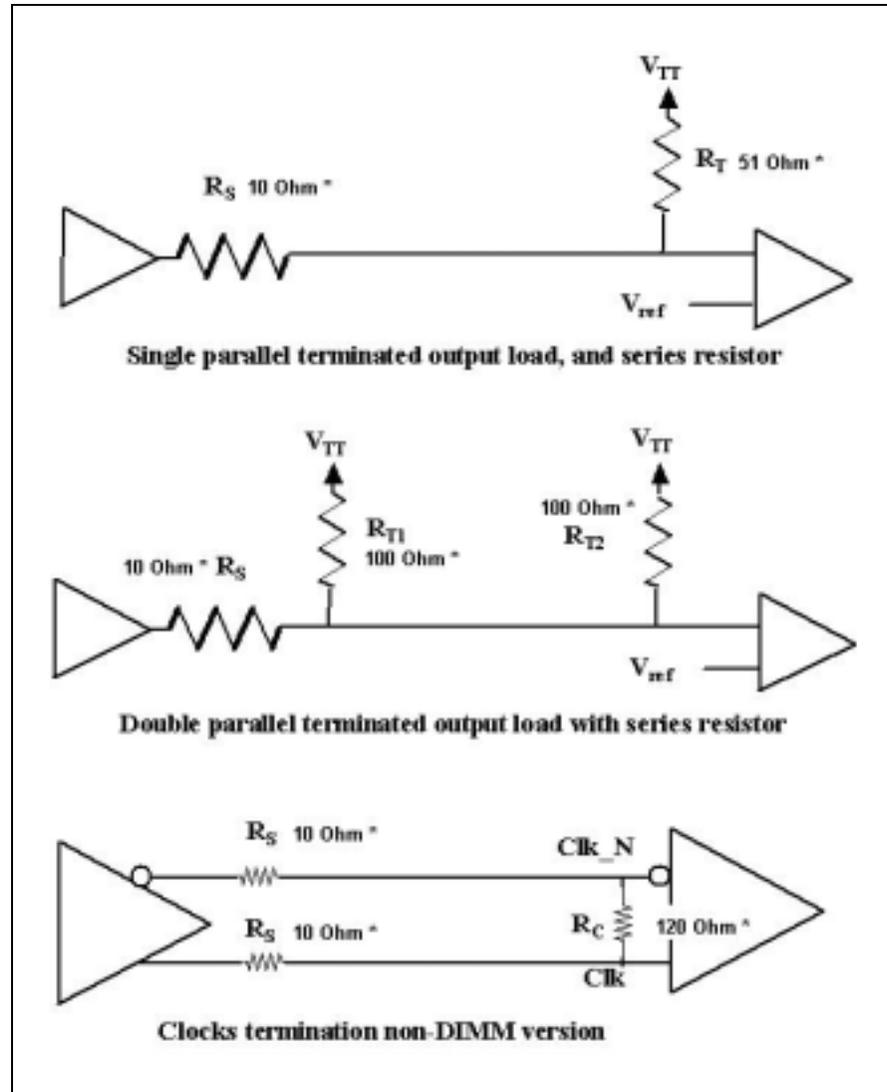
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Figure 1 Termination Circuit Examples

* Termination value recommended by IDT

PCB Routing

Proper routing of all DDR signals is absolutely essential. If proper attention is not paid to this requirement, the DDR memory subsystem is unlikely to operate at the maximum supported DDR memory subsystem frequency.

In an effort to guarantee that all designs featuring the RC32434/5 are able to operate at the highest possible frequencies, IDT strongly urges that the following layout guidelines be rigorously enforced:

DDR Clock Guidelines

- *Trace width: 10 mils.*
- *Trace space: 5 mils.*
- *Trace space to other signal group: 30 mils.*
- *Clock signals should be routed as a differential pair in a point to point topology.*
- *Match exactly the DDRCKP and DDRCKN trace lengths (a trace length mismatch of ± 20 mils is acceptable). This trace matching is necessary to meet the DDR SDRAM's input clock crossing volt-*

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age (Vix = 0.5*VDD ± 0.2 V). Match the loads between DDRCKP and DDRCKN.

- ◆ *Board designers must do careful simulations using IBIS models of the RC32434/5 drivers and DDR SDRAM receivers, as well as accurate models of the board traces and terminations, to ensure smooth clock waveforms at the DDR pins.*

DDR Address, Chip-Select, and Command Guidelines

- ◆ *Trace width: 5 mils.*
- ◆ *Trace space: 15 mils.*
- ◆ *Trace space to other signal group: 20 mils.*
- ◆ *These signals should be routed in a Daisy Chain topology if more than one DDR chip is used.*
- ◆ *Make the DDR address, chip-select, and command[1] traces <u>longer</u> than the DDR clock traces (between 1 and 2 inch longer is acceptable). For these systems, the DDR clock loads approximate the address, chip-select, and command loads. Therefore, the extra trace length will increase the Address/Command signal input hold time on the DDR side.*

DDR Data, Data-Strobe, and Data-Mask Guidelines

- ◆ *Trace width: 5 mils.*
- ◆ *Trace space: 15 mils.*
- ◆ *Trace space to other signal group: 20 mils.*
- ◆ *These signals should be routed in a Daisy Chain topology and preferable be on the same layer with no vias.*
- ◆ *DDRDQS[1:0] signals should be isolated from other signals by at least 30 mils to prevent any crosstalk.*
- ◆ *Match the DDRDQS[1:0] and DDRCKP trace lengths. This will maximize the DDRDQSx to DDRCKP setup and hold margins (i.e., tDSS and tDSH in the Jedec DDR Specification), as well as the 'write command to first DQS latching transition' margin (tDQSS in the Jedec DDR Specification). A trace length mismatch up to ± 200 mils is acceptable.*
- ◆ *Match the DDRDATA[15:0] and DDRDQS[1:0] trace lengths. In the single data strobe mode (SDS = 1)[2], the trace length of DDRDQS[0] must closely match the trace lengths of DDRDATA[15:0]. If not in single data strobe mode (SDS = 0), matching must be done between the following pairs (a trace length mismatch up to ± 50 mils is acceptable):*

    DDRDQS[0] ==> DDRDATA[7:0]

    DDRDQS[1] ==> DDRDATA[15:8]

- ◆ *Match the DDRDM[1:0] traces with the DDRDATA[15:0] lines. Specifically, match the following pairs:*

    DDRDM[0] ==> DDRDATA[7:0]

    DDRDM[1] ==> DDRDATA[15:8]

- ◆ *Board designers must do careful simulations using IBIS models to ensure the above is true[3]. Although an ideal configuration may not be achievable, the more the board layout deviates from the ideal, the less margin exists to meet DDRDM hold times with respect to DDRDQS (tDH in the Jedec DDR specification). Failure to meet the DDRDM hold times with respect to DDRDQS would require a decrease in the DDRCKP frequency in order to make the system operational.[4]*
- ◆ *Keep the read data access loop time (DDRCKP => DDRDATA) below one DDRCKP period. For*

[1.] Refers to the signals DDRADDR[13:0], DDRBA[1:0], DDRCSN, DDRRASN, DDRCASN, DDRWEN, and DDRCKE.

[2.] See SDS bit in the DDRC register.

[3.] These simulations should take into account IBIS models of the RC32434/5 drivers/receivers and DDR SDRAM drivers/receivers. Trace lengths and terminations must also be modeled accurately.

[4.] The RC32434/5's DDR Controller architecture is such that both setup and hold time margins with respect to DDRDQSx increase as the DDRCKP frequency decreases.

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example, if the DDRCKP period is 8ns, the board designer must ensure that the delay from DDRCKP (at the RC32434/5 pins) to DDRDATA (at the RC32434/5 pins) for a read transaction is below 8ns. This implies that the sum of the DDRCKP board flight time and the DDRDATA board flight time plus the DDR read data access time (tAC in the Jedec DDR Specification) has to be below one DDRCKP period.

General PCB Considerations

- *Do not route DDR signals on any layer that is not directly adjacent to a common reference plane.*
- *Place parallel termination resistors on a top layer VTT island which is at the end of the bus (VTT must be a power plane).*
- *Place the VTT generator as close as possible to the termination resistors.*

Termination and Reference Voltage Generation (VTT and Vref)

The I/O interface standard (SSTL_2) used on DDR memories uses a reference voltage to maintain the DDR signals near their switching level to increase switching speed. This is achieved by minimizing timing skew due to asymmetric logic highs versus logic lows, noise on Vref or VTT, offset of VTT relative to Vref or drift of Vref or VTT over temperature or noise.

This reference voltage (Vref) must meet several requirements in order for the DDR subsystem to operate reliably at the maximum supported DDR frequencies. The Vref requirements are:

- *Vref must track the midpoint of the signal voltage swing (generally VDDQ/2) within 3% over all valid voltage, temperature, and noise level conditions. See Figure 2 below.*
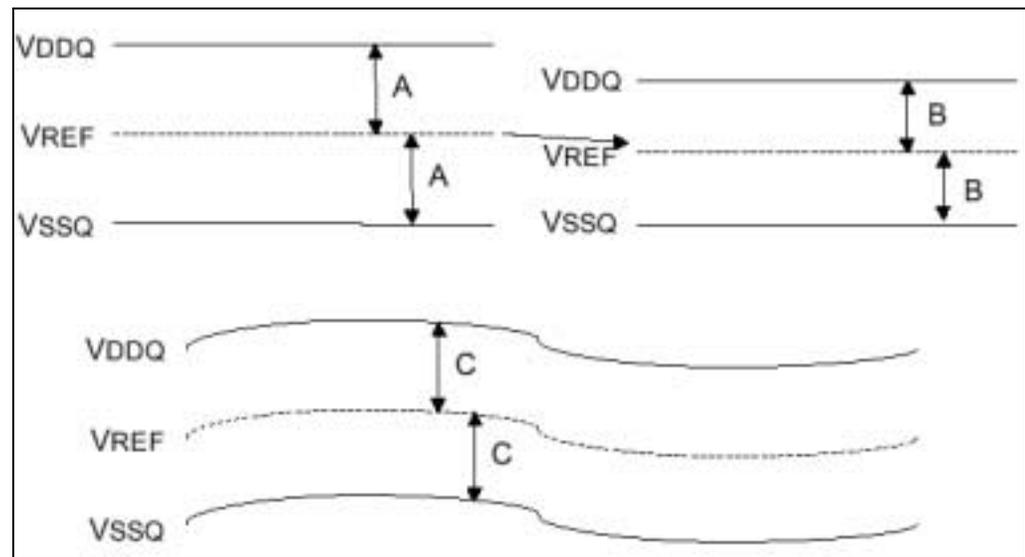

Figure 2 Vref tracking of VDD

- *Vref must use a distributed decoupling scheme to minimize capacitor ESL and localize the transient currents and returns.*
- *Vref must be isolated from other nets in order to comply with requirement #1.*
- *Vref must be decoupled from both VDD and VSS with balanced decoupling capacitors. (Again, this is necessary to meet requirement #1.)*

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These requirements can be met in several ways. The easiest way is to use a component specifically designed for this purpose. One such solution is Fairchild Semiconductor's LP2995 switching regulator. It can source or sink up to 3A of current while regulating an output VTT voltage to within 3% or less. It also provides a Vref output which fits our design bill well. One can use a simple 1% resistor divider to get the required Vref voltage at low cost and with great accuracy.

One possible implementation scheme, which successfully validated on both our validation and evaluation platforms, is shown in Figure 3. However, there are many other solutions available from other vendors which may provide comparable or even superior performance.
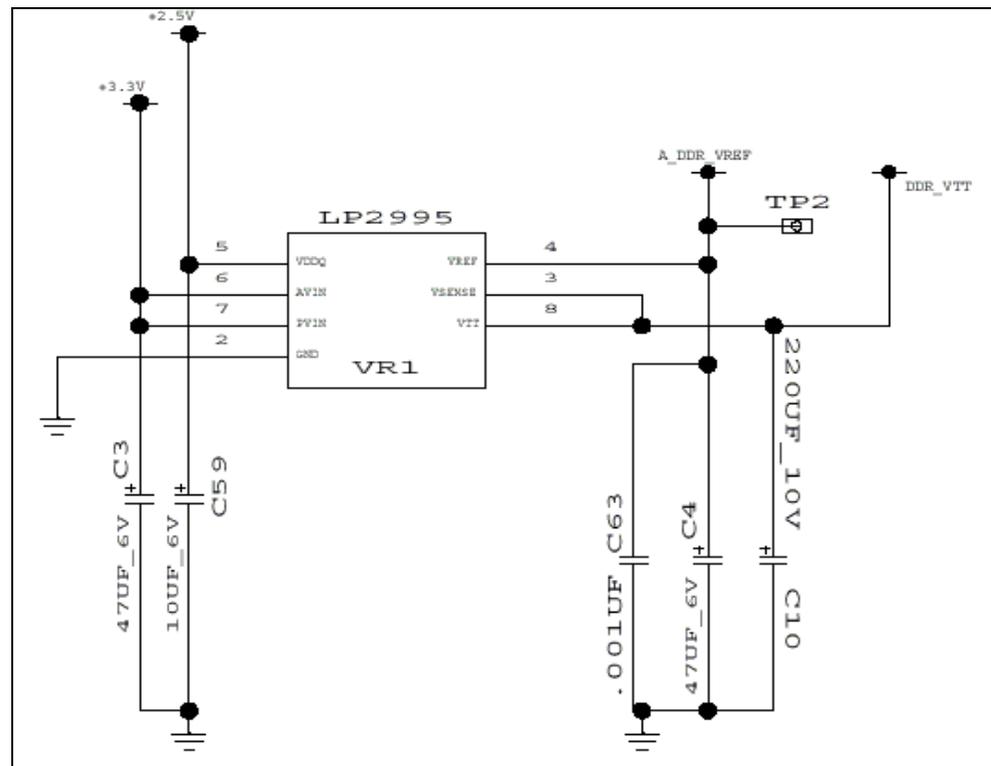

Figure 3 Vref and VTT Generation Scheme

Passive DDR Termination Scheme for Lightly Loaded Systems

In the case of very lightly loaded DDR-based systems, e.g., only one or two DDR chips with the RC32434/5 device and short traces (less than 3.5 inches), it is possible to implement a passive DDR termination scheme. In the case of a passive termination scheme:

- All pull-up terminations to DDR_VTT are optional. As a result, the designer may remove the LP2995 voltage regulator, which generates DDR_VTT, and its associated circuitry from the design.
- However, VREF (Voltage reference at +1.25V) is still required by the RC32434/5 processor as well as all DDR chips. Because VREF is usually generated by the LP2995, if the LP2995 is removed, an alternate source must be implemented. A simple divider bridge using 20K resistors in parallel with 0.1uf caps between +2.5V and GND can be used (see Figure 4).
- VREF does not need to be a power plane, since a thick trace (30mils+) is sufficient. The divider bridge should be close to the DDR chip and the CPU.

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– Series terminations are still required, however, and designers should follow the recommendations made earlier in this application note.
– Extra care should be taken regarding trace length matching, board layout, and noise prevention. Clocks, traces, and data strobes should be routed away from all other signals.

The removal of the DDR_VTT resistor packs and the voltage regulator circuitry results in a simpler board design/layout as well as some cost reduction.
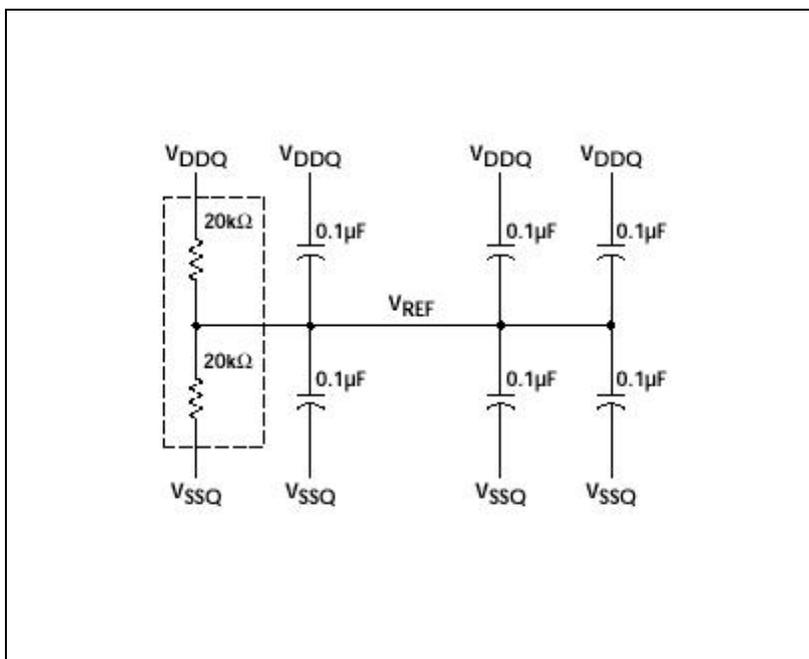

Figure 4 VREF Generation Scheme

Note: VDDQ = +2.5V

Conclusion

Successfully designing a DDR-based system is not difficult. There are adequate margins in the system to allow it to operate over all specified operating voltages, temperature ranges, and noise levels with some room to spare. However, deviations from the optimal layout, termination, or reference supply may radically reduce that margin. Hence, it is imperative that designers do their best to adhere to these guidelines. Extra care taken during the design and layout phase will result in reduced or eliminated iterations, superior system reliability, and better production yields for the finished product.